



UNITED STATES PATENT AND TRADEMARK OFFICE
Attorney Docket No. 13464US04

In the Application of:

ESIN TERZIOGLU et al.

Serial No.: 10/612,479

Filed: July 2, 2003

For: MEMORY ARCHITECTURE WITH
SINGLE PORT CELL AND DUAL
PORT (READ AND WRITE)
FUNCTIONALITY

Group Art Unit:

CERTIFICATE OF MAILING

I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450 on October 2, 2003.

By: Ronald E. Larson
Ronald E. Larson
Reg. No. 24,478

**TRANSMITTAL OF
INFORMATION DISCLOSURE STATEMENT
AFTER APPLICATION FILING DATE**

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

Pursuant to 37 C.F.R. § 1.56, it is respectfully requested that the following references be considered in the examination of the above-identified patent application:

Patent No.	Name	Date
5,170,375	Mattausch et al.	12/1992
5,752,264	Blake et al.	05/1998
5,781,498	Suh	07/1998
5,864,497	Suh	01/1999
5,995,422	Im et al.	11/1999
6,026,036	Sekiya et al.	02/2000
6,040,999	Hotta et al.	03/2000
6,084,807	Choi	07/2000
6,141,286	Vo et al.	10/2000

6,141,287	Mattausch	10/2000
6,144,604	Haller et al.	11/2000
6,154,413	Longwell et al.	11/2000
6,163,495	Ford et al.	12/2000
6,166,942	Vo et al.	12/2000
6,166,986	Kim	12/2000
6,166,989	Hamamoto et al.	12/2000
6,169,701	Eto et al.	01/2001
6,173,379	Poplingher et al.	01/2001

KIYOO ITOH et al., *Trends in Low-Power RAM Circuit Technologies*, Proceedings of the IEEE, Vol. 83, No. 4, pages 524-543, April 1995

The above-identified references are listed on the attached PTO Form 1449, and it is believed that copies of all references listed have been previously provided in the parent case, Serial No. 10/173,709, filed June 18, 2002.

This submission is in no way intended as an admission that the above-cited references constitute prior art under any subsection of 35 U.S.C. § 102. Applicant expressly retains the right to take any actions necessary to remove the above-cited references from the available prior art.

No fee is believed to be due because this statement and enclosures are being filed three months or less after the application was filed, and before the first Office Action on the merits has been mailed by the PTO. However, the Commissioner is hereby authorized to charge any additional fees which may be required or credit any overpayment to Account No. 13-0017.

Respectfully submitted,

October 2, 2003

Date

Ronald E. Larson

Ronald E. Larson

Registration No. 24,478

Attorney for Applicant

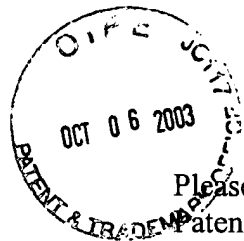
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1449A/PTO Rev. 10/95		U.S. Department of Commerce Patent and Trademark Office		Complete if Known	
LIST OF PRIOR ART CITED BY APPLICANT (use as many sheets as necessary)				Application Number	10/612,479
				Filing Date	July 2, 2003
				First Named Inventor	Esin Terzioglu et al.
				Group Art Unit	
				Examiner Name	
Sheet 1		of 1		Attorney Docket Number	13464US04

Examiner Initials*	Cite No. ¹	U.S. Patent Document		Name of Patentee or Applicant of cited Document	Date of Publication of Cited Document MM-DD-YYYY
		Number	Kind Code ² (if known)		
	1	5,170,375		Mattausch et al.	12/1992
	2	5,752,264		Blake et al.	05/1998
	3	5,781,498		Suh	07/1998
	4	5,864,497		Suh	01/1999
	5	5,995,422		Im et al.	11/1999
	6	6,026,036		Sekiya et al.	02/2000
	7	6,040,999		Hotta et al.	03/2000
	8	6,084,807		Choi	07/2000
	9	6,141,286		Vo et al.	10/2000
	10	6,141,287		Mattausch	10/2000
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	12	6,154,413		Longwell et al.	11/2000
	13	6,163,495		Ford et al.	12/2000
	14	6,166,942		Vo et al.	12/2000
	15	6,166,986		Kim	12/2000
	16	6,166,989		Hamamoto et al.	12/2000
	17	6,169,701		Eto et al.	01/2001
	18	6,173,379		Poplingher et al.	01/2001

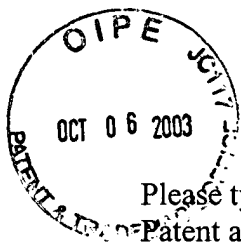
FOREIGN PATENT DOCUMENTS

Examiner Initials*	Cite No. ¹	Office ³	Foreign Patent Document		Name of Patentee or Applicant of cited Document	Date of Publication of Cited Document MM-DD-YYYY	T ⁶
			Number ⁴	Kind Code ⁵ (if known)			
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OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS

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	A	KIYOO ITOH et al., <i>Trends in Low-Power RAM Circuit Technologies</i> , Proceedings of the IEEE, Vol. 83, No. 4, pages 524-543, April 1995	
Examiner Signature		Date Considered	

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation not in conformance and not considered. Include copy of this form with next communication to applicant.



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						Group Art Unit	
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